

Toshio Kikuta

List of Publications by Year in descending order

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82
papers

1,996
citations

257450

24
h-index

243625

44
g-index

82
all docs

82
docs citations

82
times ranked

2228
citing authors

#	ARTICLE	IF	CITATIONS
1	TGS crystal as a maximum temperature thermometer. Philosophical Magazine, 2021, 101, 491-500.	1.6	0
2	Preferences of polarity and chirality in triglycine sulfate crystals by alanine ghost. Journal of Physics and Chemistry of Solids, 2021, 151, 109890.	4.0	6
3	A transverse electric current in triglycine sulphate ferroelectric crystal. Philosophical Magazine, 2016, 96, 1332-1343.	1.6	2
4	Pyroelectric properties of the triglycine sulphate crystal formerly influenced by a transverse electric field. Philosophical Magazine, 2015, 95, 289-300.	1.6	4
5	Role of Bias Electric Field for X-ray Diffraction Intensity by TGS Crystal in Transverse Electric Field. Ferroelectrics, 2015, 485, 27-33.	0.6	0
6	Influence of Transverse Electric Field on Dielectric Permittivity of Triglycine Sulfate. Ferroelectrics, 2014, 462, 39-46.	0.6	0
7	Preparation and gas sensing properties of undoped and Pd-doped TiO ₂ nanowires. Sensors and Actuators B: Chemical, 2014, 190, 838-843.	7.8	60
8	Polarization Reversal in TGS after Application of Transverse Electric Field. Ferroelectrics, 2013, 443, 88-94.	0.6	1
9	Thickness Distribution of Metal Films by Magnetron Sputtering (II) ^ ^mdash;Effect of the Distance between the Target and Substrate and the Erosion Distribution^ ^mdash;. Journal of the Vacuum Society of Japan, 2013, 56, 382-385.	0.3	0
10	Degree of Order by X-Ray Crystal Structure Analysis in Triglycine Sulfate. Ferroelectrics, 2012, 427, 119-128.	0.6	1
11	Calorimetric Study of Triglycine Sulfate after Prolonged Application of Transverse Electric Field. Ferroelectrics, 2012, 430, 30-35.	0.6	0
12	Influence of side electric potential on hysteresis loop parameters and electric permittivity in the Rochelle salt. Physica B: Condensed Matter, 2012, 407, 3956-3959.	2.7	4
13	Preparation of tungsten oxide nanowires and their application to NO ₂ sensing. Sensors and Actuators B: Chemical, 2012, 169, 113-120.	7.8	65
14	Influence of Prolonged Application of Transverse Electric Field on Remanent Polarization in Rochelle Salt. Ferroelectrics, 2012, 430, 20-29.	0.6	3
15	NO ₂ response enhancement and anomalous behavior of n-type SnO ₂ nanowires functionalized by Pd nanodots. Sensors and Actuators B: Chemical, 2012, 166-167, 671-677.	7.8	34
16	Transverse field effect close to the critical point in the TGS ferroelectric. Philosophical Magazine, 2011, 91, 3755-3765.	1.6	4
17	Thickness Distribution of Metal Films by Magnetron Sputtering. Journal of the Vacuum Society of Japan, 2011, 54, 184-187.	0.3	2
18	Synthesis of metal and metal oxide nanostructures and their application for gas sensing. Materials Chemistry and Physics, 2011, 127, 143-150.	4.0	39

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19	Influence of morphology and structure geometry on NO ₂ gas-sensing characteristics of SnO ₂ nanostructures synthesized via a thermal evaporation method. Sensors and Actuators B: Chemical, 2011, 153, 11-16.	7.8	96
20	Effect of micro-electrode geometry on NO ₂ gas-sensing characteristics of one-dimensional tin dioxide nanostructure microsensors. Sensors and Actuators B: Chemical, 2011, 156, 784-790.	7.8	36
21	Lining of cast iron cylinder with copper alloy utilising high temperature oxidation. International Journal of Cast Metals Research, 2011, 24, 124-126.	1.0	0
22	Growth and ferroelectric properties of l-, d-, and dl-methionine-doped triglycine sulfate crystals. Journal of Crystal Growth, 2010, 313, 20-25.	1.5	8
23	Catalyst supported growth of In ₂ O ₃ nanostructures and their hydrogen gas sensing properties. Sensors and Actuators B: Chemical, 2010, 147, 48-54.	7.8	86
24	Porosity Assessment of NiO Sputtered Film and NO ₂ Sensing Property. Journal of the Vacuum Society of Japan, 2010, 53, 226-229.	0.3	1
25	Annealing Effect on the Nanostructure of TiO ₂ Sputtered Film and H ₂ Sensing Property. Journal of the Vacuum Society of Japan, 2010, 53, 353-356.	0.3	0
26	Nanostructure of WO ₃ Sputtered Films Deposited at Various Gas Pressures. Journal of the Vacuum Society of Japan, 2010, 53, 210-213.	0.3	1
27	Influence of Various Amino Acids Doping on Growth and Domain Structure of Tgs Crystals. Ferroelectrics, 2010, 403, 38-44.	0.6	3
28	Order-Disorder Structure of Triglycine Sulfate Under Electric Field. Ferroelectrics, 2010, 403, 111-118.	0.6	6
29	Microstructure and H ₂ gas sensing properties of undoped and Pd-doped SnO ₂ nanowires. Sensors and Actuators B: Chemical, 2009, 135, 524-529.	7.8	188
30	Influence of effective surface area on gas sensing properties of WO ₃ sputtered thin films. Thin Solid Films, 2009, 517, 2069-2072.	1.8	149
31	Preparation of WO ₃ nanoparticles and application to NO ₂ sensor. Applied Surface Science, 2009, 256, 1050-1053.	6.1	103
32	Hydrogen sensing properties of Pd-doped SnO ₂ sputtered films with columnar nanostructures. Thin Solid Films, 2009, 517, 6119-6123.	1.8	36
33	Temperature Dependence of Dielectric Dispersion in TGS Influenced by Perpendicular Electric Field. Ferroelectrics, 2009, 384, 113-119.	0.6	2
34	A generic approach for controlled synthesis of In ₂ O ₃ nanostructures for gas sensing applications. Journal of Alloys and Compounds, 2009, 481, L35-L39.	5.5	42
35	Hydrogen sensors made of undoped and Pt-doped SnO ₂ nanowires. Journal of Alloys and Compounds, 2009, 488, L21-L25.	5.5	97
36	Fabrication and gas sensing properties of In ₂ O ₃ nanopushpins. Applied Physics Letters, 2009, 95, .	3.3	50

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37	Catalyst-free shape controlled synthesis of In ₂ O ₃ pyramids and octahedron: Structural properties and growth mechanism. <i>Journal of Alloys and Compounds</i> , 2009, 480, L9-L12.	5.5	24
38	O ₂ and CO sensing of Ga ₂ O ₃ multiple nanowire gas sensors. <i>Sensors and Actuators B: Chemical</i> , 2008, 129, 666-670.	7.8	169
39	Application of TiAl laminate to a sputtering target for TiAlN films. <i>Vacuum</i> , 2008, 83, 479-482.	3.5	1
40	Porous SnO ₂ sputtered films with high H ₂ sensitivity at low operation temperature. <i>Thin Solid Films</i> , 2008, 516, 5111-5117.	1.8	49
41	Synthesis of Titanate Nanorods by High-Temperature Oxidation. <i>Journal of Physical Chemistry C</i> , 2008, 112, 4545-4549.	3.1	14
42	Synthesis and Characterization of TeO ₂ Nanowires. <i>Japanese Journal of Applied Physics</i> , 2008, 47, 771.	1.5	41
43	Dealloying Derived Synthesis of W Nanopetal Films and Their Transformation into WO ₃ . <i>Journal of Physical Chemistry C</i> , 2008, 112, 1391-1395.	3.1	35
44	Growth and Domain Structure of TGS Crystals Doped with Various Amino Acids. <i>Ferroelectrics</i> , 2008, 368, 12-22.	0.6	4
45	Fabrication of WO ₃ Nanoflakes by a Dealloying-based Approach. <i>Chemistry Letters</i> , 2008, 37, 296-297.	1.3	8
46	Dielectric Character Modified by Perpendicular Electric Field in Triglycine Sulfate. <i>Ferroelectrics</i> , 2008, 367, 163-169.	0.6	4
47	Strange Thermal Expansion of Ferroelectric TGS in the Cryogenic Temperature Region. <i>Ferroelectrics</i> , 2008, 368, 28-35.	0.6	0
48	Crystal Structure of the Ferroelectric Phase of Triglycine Sulfate under an Electric Field. <i>Ferroelectrics</i> , 2007, 347, 65-73.	0.6	13
49	Room temperature gas sensing of p-type TeO ₂ nanowires. <i>Applied Physics Letters</i> , 2007, 90, 173119.	3.3	103
50	Microstructure and Gas Sensing Property of Porous SnO ₂ Sputtered Films. <i>Materials Science Forum</i> , 2007, 539-543, 3508-3513.	0.3	6
51	Dielectric Dispersion around the Ferroelectric Phase Transition in Partially Deuterated Glycine Phosphite. <i>Ferroelectrics</i> , 2007, 355, 204-210.	0.6	1
52	Influence of annealing on microstructure and NO ₂ -sensing properties of sputtered WO ₃ thin films. <i>Sensors and Actuators B: Chemical</i> , 2007, 128, 173-178.	7.8	90
53	Growth and internal bias field of l-lysine-doped triglycine sulfate (LLYSTGS). <i>Journal of Crystal Growth</i> , 2007, 307, 372-377.	1.5	9
54	Domain Pattern of Triglycine Sulfate after Exposure to an Electric Field Perpendicular to the Ferroelectric Axis. <i>Journal of the Korean Physical Society</i> , 2007, 51, 754.	0.7	12

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55	Ferroelectric Phase Transition Character of Glycine Phosphite. <i>Ferroelectrics</i> , 2006, 332, 13-19.	0.6	10
56	Dilatometric Study on Monoclinic Crystals of Ferroelectric TGS Down to Cryogenic Temperature Region. <i>Ferroelectrics</i> , 2006, 337, 59-69.	0.6	8
57	Lining of hydraulic cylinder made of cast iron with copper alloy. <i>Journal of Materials Processing Technology</i> , 2006, 172, 30-34.	6.3	15
58	H ₂ S sensing property of porous SnO ₂ sputtered films coated with various doping films. <i>Vacuum</i> , 2006, 80, 723-725.	3.5	55
59	Deuteration Effect on the Ferroelectric Phase Transition of TAAP. <i>Ferroelectrics</i> , 2006, 337, 95-103.	0.6	5
60	Effective Surface Area of SnO ₂ -Sputtered Films Evaluated by Measurement of Physical Adsorption Isotherms. <i>Japanese Journal of Applied Physics</i> , 2006, 45, 9180-9184.	1.5	15
61	Lining of Cast Iron Cylinder with Copper Alloy. <i>Advanced Materials Research</i> , 2006, 15-17, 888-893.	0.3	0
62	Influence of an Electric Field Perpendicular to the Ferroelectric Axis on the Dielectric Properties of Triglycine Sulfate. <i>Ferroelectrics</i> , 2006, 336, 91-100.	0.6	18
63	Effect of density and thickness on H ₂ -gas sensing property of sputtered SnO ₂ films. <i>Vacuum</i> , 2005, 77, 237-243.	3.5	36
64	Dependence of NO ₂ gas sensitivity of WO ₃ sputtered films on film density. <i>Thin Solid Films</i> , 2005, 474, 255-260.	1.8	42
65	Polarization reversal of telluric acid ammonium phosphate. <i>Materials Science and Engineering B: Solid-State Materials for Advanced Technology</i> , 2005, 120, 134-136.	3.5	3
66	NO ₂ Gas Sensor Made of Porous MoO ₃ Sputtered Films. <i>Japanese Journal of Applied Physics</i> , 2005, 44, 792-795.	1.5	12
67	Influence of Uniaxial Pressure on the Phase Transition of Partially Deuterated Glycinium Phosphite. <i>Ferroelectrics</i> , 2004, 302, 99-104.	0.6	1
68	Dielectric Dispersion in the Middle of Polarization Reversal in Triglycine Sulfate Crystals. <i>Ferroelectrics</i> , 2003, 290, 187-192.	0.6	1
69	Simple Model using Gas Sensor Characteristics of each Component Gas to Estimate Individual Gas Concentrations in Gas Mixtures. <i>Japanese Journal of Applied Physics</i> , 2003, 42, 1538-1544.	1.5	0
70	Exact Determination of the Polar Direction in Lithium Trihydrogen Selenite Ferroelectric Crystal. <i>Japanese Journal of Applied Physics</i> , 2003, 42, 6483-6485.	1.5	0
71	Ferroelectric Properties of Deuterated Glycine Phosphite. <i>Ferroelectrics</i> , 2002, 269, 153-158.	0.6	20
72	Dielectric Dispersion of Triglycine Sulfate at Ferroelectric Phase. <i>Ferroelectrics</i> , 2002, 272, 351-356.	0.6	4

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73	Phase transition of copper-doped triglycine sulfate. <i>Ferroelectrics</i> , 2001, 262, 119-124.	0.6	5
74	Superlattice structure of ars in the polar phase. <i>Ferroelectrics</i> , 2001, 261, 245-250.	0.6	0
75	Slit Structure as a Countermeasure for the Thermal Deformation of a Metal Mask. <i>Japanese Journal of Applied Physics</i> , 2001, 40, 7170-7173.	1.5	2
76	Preparation of Ferroelectric Glycine Phosphite Single Crystals. <i>Japanese Journal of Applied Physics</i> , 2000, 39, 6612-6613.	1.5	9
77	Structural change in the paraelectric phase of ammonium Rochelle salt. <i>Ferroelectrics</i> , 1999, 229, 189-194.	0.6	1
78	X-Ray diffraction intensity of ammonium rochelle salt having domain structure. <i>Ferroelectrics</i> , 1999, 222, 243-247.	0.6	1
79	Domain structure in the polar phase of ammonium rochelle salt. <i>Ferroelectrics</i> , 1997, 190, 51-56.	0.6	5
80	Molecular motion of PO ₄ in KDP at ferroelectric phase transition. <i>Ferroelectrics</i> , 1995, 170, 17-22.	0.6	2
81	A calorimetric study of RS _{1-x} ARS _x mixed crystal system (0.9 ≤ x ≤ 1.0). <i>Ferroelectrics</i> , 1995, 168, 169-175.	0.6	5
82	Dielectric properties and phase transition in cesium tetrachlorozincate Cs ₂ ZnCl ₄ . <i>Ferroelectrics</i> , 1992, 125, 141-146.	0.6	9